Look-Ahead Carry Block

The MC14582B is a CMOS look—ahead carry generator capable of anticipating a carry across four binary adders or groups of adders. The device is cascadable to perform full look—ahead across n—bit adders. Carry, generate—carry, and propagate—carry functions are provided as enumerated in the pin designation table shown below.

- · Expandable to any Number of Bits
- · All Buffered Outputs
- · Low Power Dissipation
- Diode Protection on All Inputs
- Supply Voltage Range = 3.0 Vdc to 18 Vdc
- Capable of Driving Two Low–power TTL Loads or One Low–Power Schottky TTL Load over the Rated Temperature Range

MAXIMUM RATINGS* (Voltages Referenced to VSS)

Symbol	Parameter	Value	Unit
V _{DD}	DC Supply Voltage	- 0.5 to + 18.0	V
V _{in} , V _{out}	Input or Output Voltage (DC or Transient)	-0.5 to $V_{DD} + 0.5$	V
I _{in} , I _{out}	Input or Output Current (DC or Transient), per Pin	± 10	mA
PD	Power Dissipation, per Package†	500	mW
T _{stg}	Storage Temperature	- 65 to + 150	°C
TL	Lead Temperature (8–Second Soldering)	260	°C

^{*} Maximum Ratings are those values beyond which damage to the device may occur. †Temperature Derating:

Plastic "P and D/DW" Packages: – 7.0 mW/°C From 65°C To 125°C Ceramic "L" Packages: – 12 mW/°C From 100°C To 125°C

LOGIC EQUATIONS

$$\begin{split} &C_{n+x} = \overline{G0} + (\overline{P0} \bullet C_n) \\ &C_{n+y} = \overline{G1} + (\overline{P1} \bullet \overline{G0}) + (\overline{P1} \bullet \overline{P0} \bullet C_n) \\ &C_{n+z} = \overline{G2} + (\overline{P2} \bullet \overline{G1}) + (\overline{P2} \bullet \overline{P1} \ \overline{G0}) + (\overline{P2} \bullet \overline{P1} \bullet \overline{P0} \bullet C_n) \\ &\overline{G} = \overline{G3} + (\overline{P3} \bullet \overline{G2}) + (\overline{P3} \bullet \overline{P2} \bullet \overline{G1}) + (\overline{P1} \bullet \overline{P2} \bullet \overline{P3} \bullet \overline{G0}) \\ &\overline{P} = \overline{P3} \bullet \overline{P2} \bullet \overline{P1} \bullet \overline{P0} \end{split}$$

PIN DESIGNATIONS

Designation	Pin No's	Function
$\overline{G0}, \overline{G1}, \overline{G2}, \overline{G3}$	3, 1, 14, 5	Active–Low Carry–Generate Inputs
P0, P1, P2, P3	4, 2, 15, 6	Active–Low Carry–Propagate Inputs
C _n	13	Carry Input
C _{n+x} , C _{n+y} C _{n+z}	12, 11, 9	Carry Outputs
G	10	Active–Low Group Carry–Generate Output
P	7	Active–Low Group Carry–Propagate Output

MC14582B



L SUFFIX CERAMIC CASE 620



P SUFFIX PLASTIC CASE 648



D SUFFIX SOIC CASE 751B

ORDERING INFORMATION

MC14XXXBCP Plastic MC14XXXBCL Ceramic MC14XXXBD SOIC

 $T_A = -55^{\circ}$ to 125° C for all packages.

PIN ASSIGNMENT 16 | V_{DD} P1 I 15 P2 G0 🛛 3 14 | G2 ₱0 fl 4 13 C_{in} 12 🛭 C_{n+x} G3 🛮 5 ₽3 I 11 C_{n+v} P 10 ∏ G 9 🛚 C_{n+z} VSS [

ELECTRICAL CHARACTERISTICS (Voltages Referenced to V_{SS})

			V _{DD}	- 5	5°C		25°C		125	i°C	
Characteristic		Symbol	Vdc	Min	Max	Min	Typ #	Max	Min	Max	Unit
Output Voltage V _{in} = V _{DD} or 0	"0" Level	VOL	5.0 10 15	_ _ _	0.05 0.05 0.05	_ _ _	0 0 0	0.05 0.05 0.05	_ _ _	0.05 0.05 0.05	Vdc
V _{in} = 0 or V _{DD}	"1" Level	VOH	5.0 10 15	4.95 9.95 14.95	_ _ _	4.95 9.95 14.95	5.0 10 15	_ _ _	4.95 9.95 14.95	_ _ _	Vdc
Input Voltage (V _O = 4.5 or 0.5 Vdc) (V _O = 9.0 or 1.0 Vdc) (V _O = 13.5 or 1.5 Vdc)	"0" Level	V _I L	5.0 10 15	_ _ _	1.5 3.0 4.0	_ _ _	2.25 4.50 6.75	1.5 3.0 4.0	_ _ _	1.5 3.0 4.0	Vdc
$(V_O = 0.5 \text{ or } 4.5 \text{ Vdc})$ $(V_O = 1.0 \text{ or } 9.0 \text{ Vdc})$ $(V_O = 1.5 \text{ or } 13.5 \text{ Vdc})$	"1" Level	VIH	5.0 10 15	3.5 7.0 11		3.5 7.0 11	2.75 5.50 8.25		3.5 7.0 11		Vdc
Output Drive Current (V _{OH} = 2.5 Vdc) (V _{OH} = 4.6 Vdc) (V _{OH} = 9.5 Vdc) (V _{OH} = 13.5 Vdc)	Source	ІОН	5.0 5.0 10 15	- 3.0 - 0.64 - 1.6 - 4.2	_ _ _ _	- 2.4 - 0.51 - 1.3 - 3.4	- 4.2 - 0.88 - 2.25 - 8.8	_ _ _ _	- 1.7 - 0.36 - 0.9 - 2.4	_ _ _ _	mAdc
$(V_{OL} = 0.4 \text{ Vdc})$ $(V_{OL} = 0.5 \text{ Vdc})$ $(V_{OL} = 1.5 \text{ Vdc})$	Sink	lOL	5.0 10 15	0.64 1.6 4.2	_ _ _	0.51 1.3 3.4	0.88 2.25 8.8	_ _ _	0.36 0.9 2.4	_ _ _	mAdc
Input Current		l _{in}	15	_	±0.1	_	±0.00001	±0.1	_	±1.0	μAdc
Input Capacitance (V _{in} = 0)		C _{in}	_	_	_	_	5.0	7.5	_	_	pF
Quiescent Current (Per Package)		I _{DD}	5.0 10 15	_ _ _	5.0 10 20	_ _ _	0.005 0.010 0.015	5.0 10 20	_ _ _	150 300 600	μAdc
Total Supply Current**† (Dynamic plus Quiesce Per Package) (C _L = 50 pF on all outp buffers switching)		lΤ	5.0 10 15			$I_T = (2$.4 μA/kHz) f 2.8 μA/kHz) f I.3 μA/kHz) f	+ I _{DD}			μAdc

#Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

$$I_T(C_L) = I_T(50 \text{ pF}) + (C_L - 50) \text{ Vfk}$$

where: IT is in μ A (per package), CL in pF, V = (VDD - VSS) in volts, f in kHz is input frequency, and k = 0.005.

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range $V_{SS} \le (V_{in} \text{ or } V_{out}) \le V_{DD}$. Unused inputs must always be tied to an appropriate logic voltage level (e.g., either V_{SS} or V_{DD}). Unused outputs must

be left open.

^{**} The formulas given are for the typical characteristics only at 25 $^{\circ}\text{C}.$

[†]To calculate total supply current at loads other than 50 pF:

SWITCHING CHARACTERISTICS* ($C_L = 50 \text{ pF}, T_A = 25^{\circ}C$)

Characteristic	Symbol	V _{DD}	Min	Тур#	Max	Unit
Output Rise and Fall Time t _{TLH} , t _{THL} = (1.5 ns/pF) C _L + 25 ns t _{TLH} , t _{THL} = (0.75 ns/pF) C _L + 12.5 ns t _{TLH} , t _{THL} = (0.55 ns/pF) C _L + 9.5 ns	t _{TLH} , t _{THL}	5.0 10 15		100 50 40	200 100 80	ns
Propagation Delay Time tpLH, tpHL = (1.7 ns/pF) C _L + 260 ns tpLH, tpHL = (0.66 ns/pF) C _L + 107 ns tpLH, tpHL = (0.5 ns/pF) C _L + 85 ns	tpLH, ^t PHL	5.0 10 15	_ _ _	345 140 110	690 280 220	ns

^{*}The formulas given are for the typical characteristics only at 25°C.

[#]Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

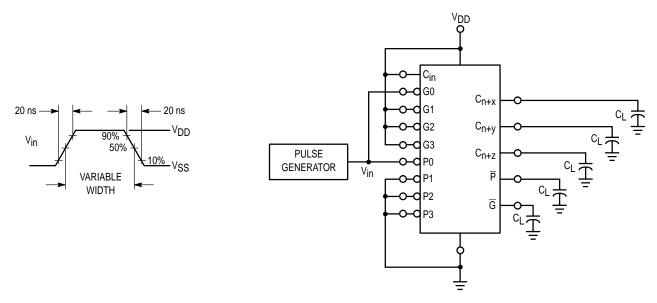


Figure 1. Dynamic Power Dissipation Test Circuit and Waveform

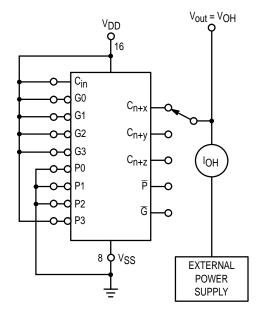


Figure 2. Source Current Test Circuit

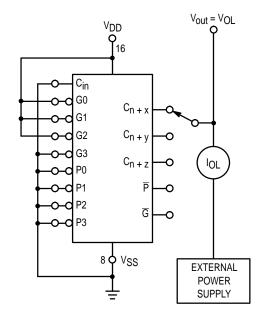
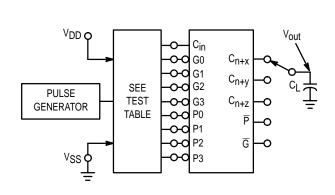
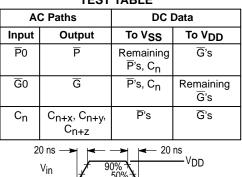


Figure 3. Sink Current Test Circuit

TEST TABLE





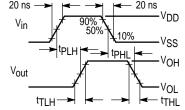
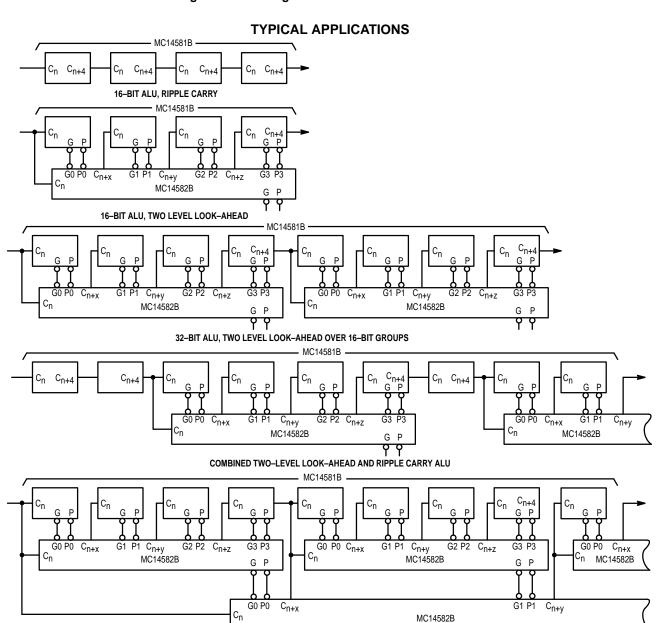


Figure 4. Switching Time Test Circuit and Waveforms

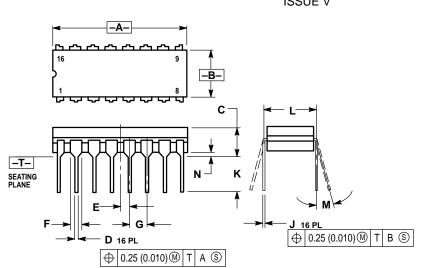


64-BIT ALU, FULL-CARRY LOOK-AHEAD IN THREE LEVELS.

A AND B INPUTS AND F OUTPUTS ARE NOT SHOWN (MC14581B).

OUTLINE DIMENSIONS

L SUFFIX CERAMIC DIP PACKAGE CASE 620-10 ISSUE V



NOTES:

- NOTES:

 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: INCH.

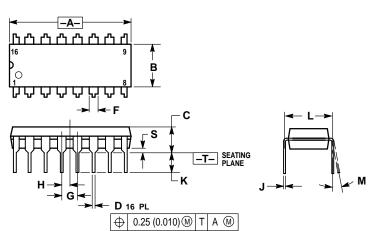
 3. DIMENSION L TO CENTER OF LEAD WHEN FORMED PARALLEL.

 4. DIMENSION F MAY NARROW TO 0.76 (0.030) WHERE THE LEAD ENTERS THE CERAMIC RODY.

	INCHES		MILLIN	IETERS		
DIM	MIN MAX		MIN	MAX		
Α	0.750	0.785	19.05	19.93		
В	0.240	0.295	6.10	7.49		
C		0.200		5.08		
D	0.015	0.020	0.39	0.50		
Е	0.050 BSC		1.27 BSC			
F	0.055	0.065	1.40	1.65		
G	0.100 BSC		2.54 BSC			
Н	0.008	0.015	0.21	0.38		
K	0.125	0.170	3.18	4.31		
L	0.300 BSC		7.62	BSC		
M	0 °	15°	0 °	15°		
N	0.020	0.040	0.51	1.01		

P SUFFIX

PLASTIC DIP PACKAGE CASE 648-08 ISSUE R



NOTES:

- NOTES:

 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: INCH.

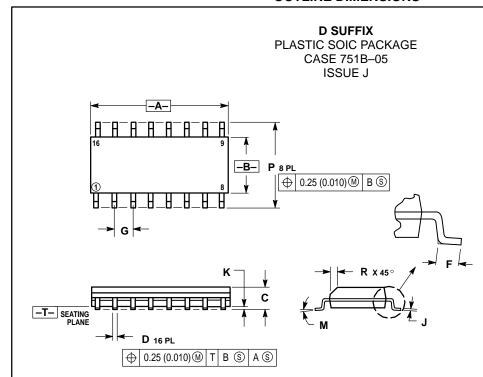
 3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.

 4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.

 5. ROUNDED CORNERS OPTIONAL.

	INC	HES	MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.740	0.770	18.80	19.55	
В	0.250	0.270	6.35	6.85	
С	0.145	0.175	3.69	4.44	
D	0.015	0.021	0.39	0.53	
F	0.040	0.70	1.02	1.77	
G	0.100	BSC	2.54 BSC		
Н	0.050	BSC	1.27 BSC		
J	0.008	0.015	0.21	0.38	
K	0.110	0.130	2.80	3.30	
L	0.295	0.305	7.50	7.74	
M	0°	10°	0°	10 °	
S	0.020	0.040	0.51	1.01	

OUTLINE DIMENSIONS



NOTES

- DIMENSIONING AND TOLERANCING PER ANSI
- 2. CONTROLLING DIMENSION: MILLIMETER.
- DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
- MAXIMUM MOLD PROTRUSION 0.15 (0.006)
 PER SIDE.
- 5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIN	METERS	INC	HES	
DIM	MIN	MAX	MIN	MAX	
Α	9.80	10.00	0.386	0.393	
В	3.80	4.00	0.150	0.157	
С	1.35	1.75	0.054	0.068	
D	0.35	0.49	0.014	0.019	
F	0.40	1.25	0.016	0.049	
G	1.27	BSC	0.050 BSC		
J	0.19	0.25	0.008	0.009	
K	0.10	0.25	0.004	0.009	
М	0°	7°	0°	7°	
Р	5.80	6.20	0.229	0.244	
R	0.25	0.50	0.010	0.019	

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How to reach us

USA/EUROPE/Locations Not Listed: Motorola Literature Distribution; P.O. Box 20912; Phoenix, Arizona 85036. 1–800–441–2447 or 602–303–5454

MFAX: RMFAX0@email.sps.mot.com – TOUCHTONE 602–244–6609 INTERNET: http://Design_NET.com

JAPAN: Nippon Motorola Ltd.; Tatsumi–SPD–JLDC, 6F Seibu–Butsuryu–Center, 3–14–2 Tatsumi Koto–Ku, Tokyo 135, Japan. 03–81–3521–8315

ASIA/PACIFIC: Motorola Semiconductors H.K. Ltd.; 8B Tai Ping Industrial Park, 51 Ting Kok Road, Tai Po, N.T., Hong Kong. 852–26629298



